NSN 5961-00-436-1001

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-436-1001 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-71 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source all transistor and 50.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source all transistor **Current Rating Per Characteristic:** 50.00 milliamperes gate current all transistor **Power Rating Per Characteristic:** 250.0 milliwatts total power dissipation all transistor **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No